

**SN54BCT2240, SN74BCT2240**  
**OCTAL BUFFERS AND LINE DRIVERS/MOS DRIVERS**  
**WITH 3-STATE OUTPUTS**

D3057, SEPTEMBER 1988—REVISED JULY 1989

- **BiCMOS Design Substantially Reduces Standby Current**
- **Output Ports have Equivalent 33- $\Omega$  Series Resistors so No External Resistors are Required**
- **ESD Protection Exceeds 2000 V, MIL-STD-883C, Method 3015**
- **3-State Outputs Drive Bus Lines or Buffer Memory Address Registers**
- **Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs**
- **Dependable Texas Instruments Quality and Reliability**

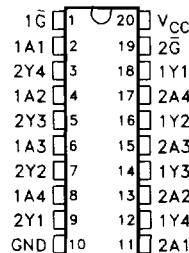
#### description

These octal buffers and line drivers are designed specifically to improve both the performance and density of three-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. Taken together with the 'BCT2241 and 'BCT2244, these devices provide the choice of selected combinations of inverting and noninverting outputs, symmetrical  $\bar{G}$  (active-low output control) inputs, and complementary G and  $\bar{G}$  inputs. These devices feature high fan-out and improved fan-in.

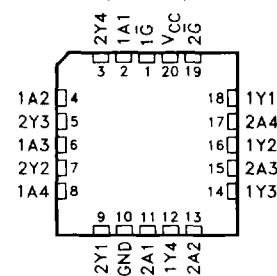
The SN54BCT2240 is characterized for operation over the full military temperature range of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The SN74BCT2240 is characterized for operation from  $0^{\circ}\text{C}$  to  $70^{\circ}\text{C}$ .

**SN54BCT2240 ... J PACKAGE**  
**SN74BCT2240 ... DW OR N PACKAGE**

(TOP VIEW)



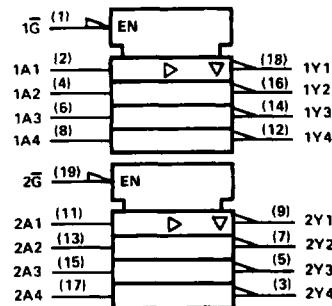
**SN54BCT2240 ... FK PACKAGE**  
**(TOP VIEW)**



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#### logic symbol†



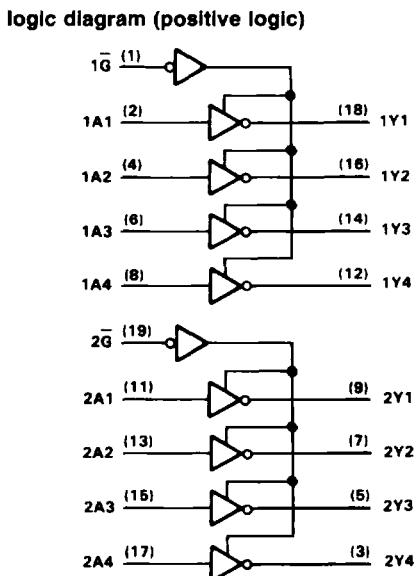
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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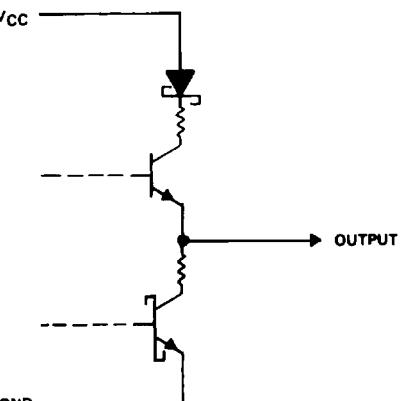
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OCTAL BUFFERS AND LINE DRIVERS/MOS DRIVERS  
WITH 3-STATE OUTPUTS**



### **schematic of each output**



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**NOTE 1:** The input negative-voltage rating may be exceeded if the input clamp current rating is observed.

#### **recommended operating conditions**

		SN54BCT2240			SN74BCT2240			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V <sub>CC</sub>	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
V <sub>IH</sub>	High-level input voltage		2			2		V
V <sub>IL</sub>	Low-level input voltage			0.8			0.8	V
I <sub>IK</sub>	Input clamp current			-18			-18	mA
I <sub>OH</sub>	High-level output current			12			-12	mA
I <sub>OL</sub>	Low-level output current			12			12	mA
T <sub>A</sub>	Operating free-air temperature	-55		125	0		70	°C



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**electrical characteristics over recommended operating free-air temperature range  
 (unless otherwise noted)**

PARAMETER	TEST CONDITIONS			SN54BCT2240			SN74BCT2240			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V <sub>IK</sub>	V <sub>CC</sub> = 4.5 V,	I <sub>OH</sub> = -18 mA				-1.2			-1.2	V
V <sub>OH</sub>	V <sub>CC</sub> = 4.5 V	I <sub>OH</sub> = -1 mA		2.4	3.3		2.4	3.3		V
		I <sub>OH</sub> = -12 mA		2	3.2		2	3.2		
V <sub>OL</sub>	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 1 mA		0.15	0.5		0.15	0.5		V
		I <sub>OL</sub> = 12 mA		0.35	0.8		0.35	0.8		
I <sub>I</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 5.5 V				0.1			0.1	mA
I <sub>IH</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 2.7 V				20			20	μA
I <sub>IL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.5 V				-1			-1	mA
I <sub>OZH</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.7 V				50			50	μA
I <sub>OZL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0.5 V				-50			-50	μA
I <sub>OS</sub> ‡	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0		-100	-225		-100	-225		mA
I <sub>ICCH</sub>	V <sub>CC</sub> = 5.5 V, Outputs open					19	32		19	32
I <sub>ICCL</sub>						46	76		46	76
I <sub>ICCZ</sub>						6	8		6	8

† All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.

‡ Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

**switching characteristics (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 5 V, C <sub>L</sub> = 50 pF, R <sub>1</sub> = 500 Ω, R <sub>2</sub> = 500 Ω, T <sub>A</sub> = 25°C				V <sub>CC</sub> = 4.5 V to 5.5 V, C <sub>L</sub> = 50 pF, R <sub>1</sub> = 500 Ω, R <sub>2</sub> = 500 Ω, T <sub>A</sub> = MIN to MAX				UNIT
			'BCT2240			SN54BCT2240	SN74BCT2240				
			MIN	TYP	MAX	MIN	MAX	MIN	MAX		
I <sub>PLH</sub>	A	Y	0.5	3.4	4.8	0.5	6.3	0.5	5.7	ns	
			0.5	2.8	4	0.5	4.6	0.5	4.4		
I <sub>PHL</sub>	G	Y	2.6	6.2	8.2	2.6	10.1	2.6	9.3	ns	
			4.3	8.8	10.9	4.3	12.9	4.3	12.4		
I <sub>PZH</sub>	G	Y	2	5.3	7.1	2	9.2	2	8.7	ns	
			2.2	6.7	8.5	2.2	12.2	2.2	10.6		
I <sub>PZL</sub>											

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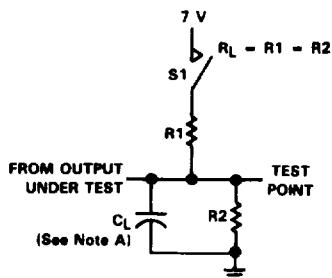
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**PARAMETER MEASUREMENT INFORMATION**

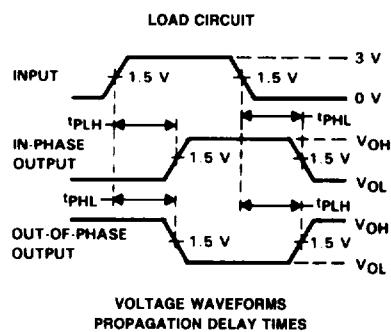


SWITCH POSITION TABLE

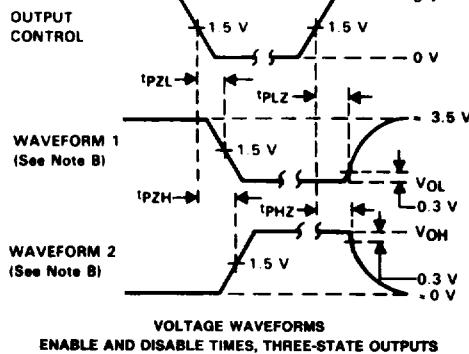
TEST	S1
t <sub>PLH</sub>	Open
t <sub>PHL</sub>	Open
t <sub>PZH</sub>	Open
t <sub>PZL</sub>	Closed
t <sub>PHZ</sub>	Open
t <sub>PLZ</sub>	Closed

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VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES, THREE-STATE OUTPUTS

NOTES: A.  $C_L$  includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.

Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

C. All input pulses are supplied by the generators having the following characteristics: PRR < 10 MHz,  $Z_o = 50 \Omega$ ,  $t_r \leq 2.5 \text{ ns}$ ,  $t_f \leq 2.5 \text{ ns}$ .

D. The outputs are measured one at a time with one transition per measurement.

**FIGURE 1. SWITCHING CHARACTERISTICS**